

Schottky Barrier Diode

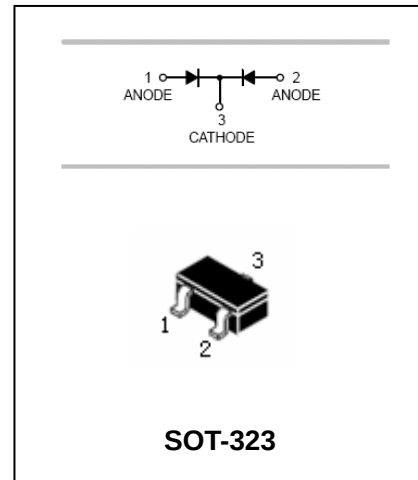
RB715F

FEATURES

- Extra small power mold type.
- Low V_F .
- High reliability.



Lead-free



APPLICATIONS

- General purpose application.

ORDERING INFORMATION

Type No.	Marking	Package Code
RB715F	3D	SOT-323

MAXIMUM RATING @ $T_a=25^\circ\text{C}$ unless otherwise specified

Parameter	Symbol	Limits	Unit
Peak reverse voltage	V_{RM}	40	V
Diode reverse voltage	V_R	40	V
Average forward current	I_F	30	mA
Forward Surge Current $t=1\mu\text{S}$	I_{FS}	200	mA
Power Dissipation	P_d	150	mW
Junction temperature	T_j	125	$^\circ\text{C}$
Storage temperature range	T_{stg}	-40-+125	$^\circ\text{C}$

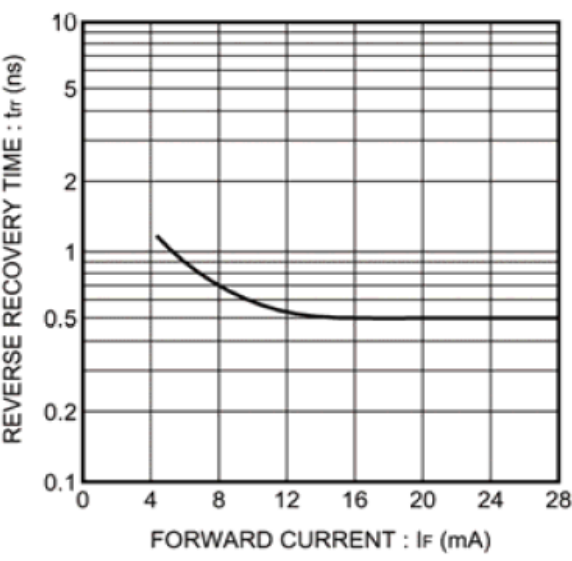
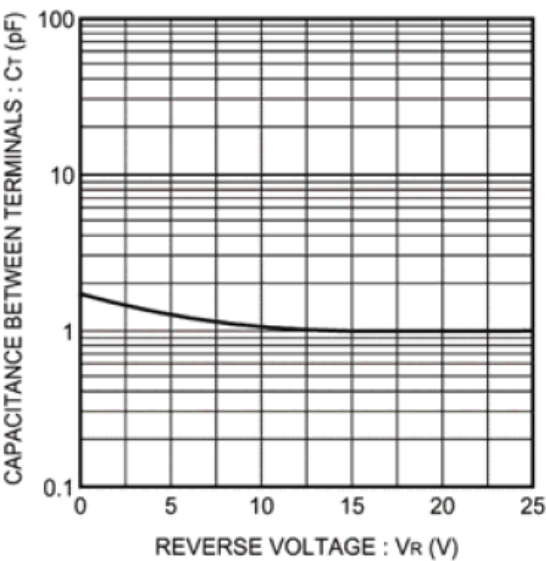
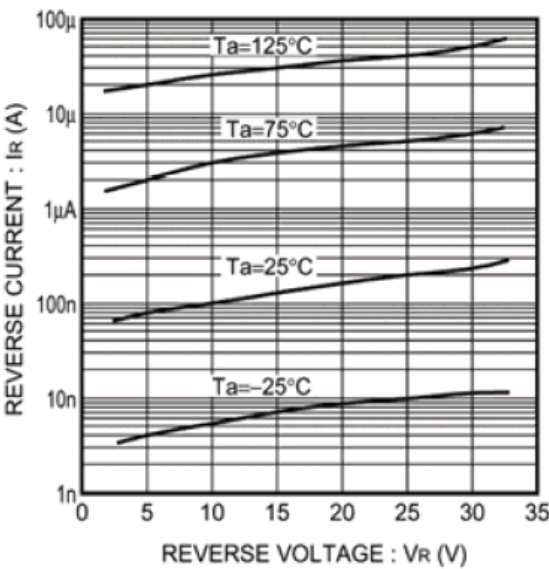
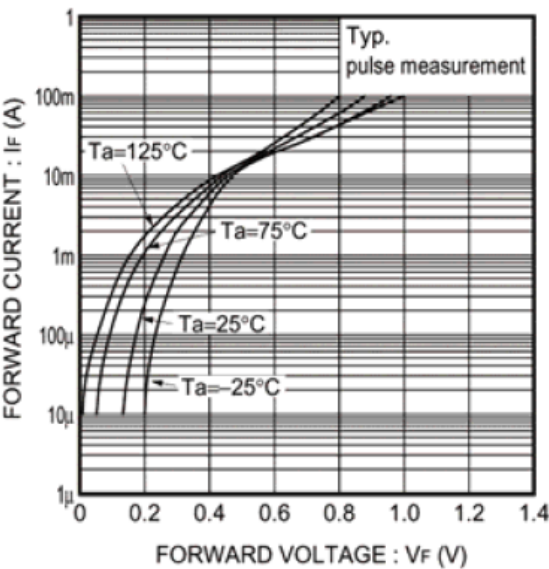
ELECTRICAL CHARACTERISTICS @ $T_a=25^\circ\text{C}$ unless otherwise specified

Parameter	Symbol	Test conditions	MIN	MAX	UNIT
Reverse breakdown voltage	$V_{(BR)R}$	$I_R=100\mu\text{A}$	40		V
Reverse voltage leakage current	I_R	$V_R=10\text{V}$		1	μA
Forward voltage	V_F	$I_F=1\text{mA}$		370	mV
Diode capacitance	C_D	$V_R=1\text{V}$ $f=1\text{MHz}$		2.0	pF

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TYPICAL CHARACTERISTICS @ Ta=25°C unless otherwise specified



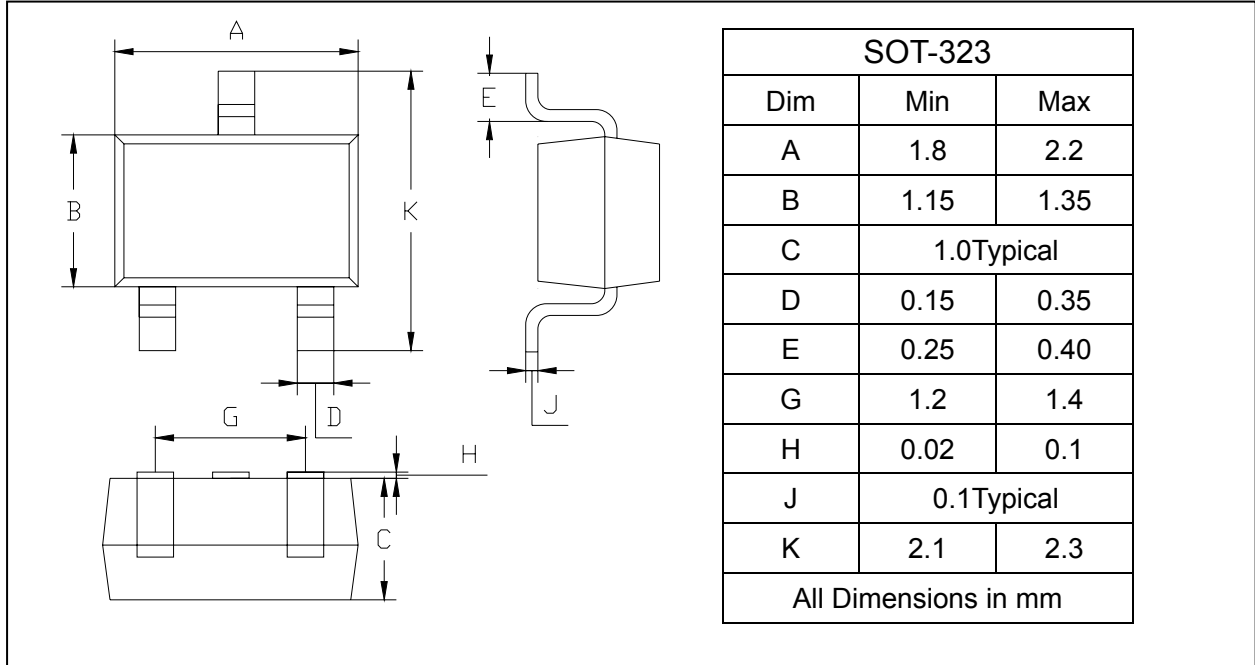
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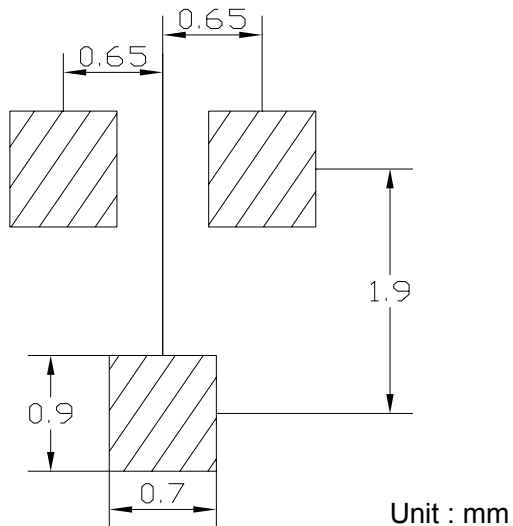
PACKAGE OUTLINE

Plastic surface mounted package

SOT-323



SOLDERING FOOTPRINT



PACKAGE INFORMATION

Device	Package	Shipping
RB715F	SOT-323	3000/Tape&Reel